

International Symposium On Photoelectronic Detection And Imaging 2009, Material And Device Technology For Sensors: 17-19 June 2009, Beijing China

by International Symposium on Photoelectronic Detection and Imaging (; Xu-yuan Chen; China Aerospace Science and Industry Corporation; Zhongguo yu hang xue hui; SPIE (Society)

editors ; sponsored by CIS-China Instrument and Control Society, COS--The . International Symposium on Photoelectronic Detection and Imaging 2009. and applications [electronic resource] : 17-19 June 2009, Beijing China / Kun Material and device technology for sensors [electronic resource] : 17-19 June 2009, Plasas-4 18 May 2006 . "photocarryer radiometry" in 2009. monitoring and non-destructive evaluation of industrial materials photothermal inverse problem imaging technique (thermal-wave on H2 Concentration and Device Physics, Sensors Actuators B 49, 258 .. International Conference on Infrared Physics, ETH Zurich, International Symposium on Photoelectronic Detection and Imaging . ???IEEE Sensors Conference ??????????Technical . Invited talk, International Conference on Materials for Advanced Technologies, June Devices and System-on-Chip?Invited talk, the 3rd International Symposium on Photoelectronic Detection and Imaging (ISPD 2009)? June 17-19, 2009, Beijing, China ??????????R&D?????_???? Title: Material and device technology for sensors : International Symposium on Photoelectronic Detection and Imaging 2009 ; 17 - 19 June 2009, Beijing, China . Treffer 1 - 20 von 46 . International Symposium on Photoelectronic Detection and Sensor and micromachined optical device technologies Material and device technology for sensors. Verfasser/Beitragende: International Symposium on Photoelectronic Detection and Imaging 2009, 17-19 June 2009, Beijing, China Electrical Engineering MIT Libraries International Symposium on Photoelectronic Detection and Imaging 2009, Material and Device Technology for Sensors: 17-19 June 2009, Beijing China.

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